Sensitive Gate Triacs

Silicon Bidirectional Thyristors

Designed for industrial and consumer applications for full wave control of AC loads such as appliance controls, heater controls, motor controls, and other power switching applications.

Features

- Sensitive Gate Allows Triggering by Microcontrollers and other Logic Circuits
- Blocking Voltage to 800 Volts
- On-State Current Rating of 12 Amperes RMS at 70°C
- High Surge Current Capability 90 Amperes
- Rugged, Economical TO-220AB Package
- Glass Passivated Junctions for Reliability and Uniformity
- Maximum Values of IGT, VGT and IH Specified for Ease of Design
- High Commutating di/dt 8.0 A/ms Minimum at 110°C
- Immunity to dV/dt 15 V/μsec Minimum at 110°C
- Operational in Three Quadrants: Q1, Q2, and Q3
- These Devices are Pb-Free and are RoHS Compliant*

MAXIMUM RATINGS (T_J = 25°C unless otherwise noted)

Rating	Symbol	Value	Unit
Peak Repetitive Off–State Voltage (Note 1) (T _J = -40 to 110°C, Sine Wave, 50 to 60 Hz, Gate Open) MAC12SM MAC12SN	V _{DRM,} V _{RRM}	600 800	\ \
On-State RMS Current (All Conduction Angles; T _C = 70°C)	I _{T(RMS)}	12	А
Peak Non-Repetitive Surge Current (One Full Cycle Sine Wave, 60 Hz, T _J = 110°C)	I _{TSM}	90	A
Circuit Fusing Consideration (t = 8.33 ms)	l ² t	33	A ² sec
Peak Gate Power (Pulse Width = 1.0 μsec, T _C = 70°C)	P _{GM}	16	W
Average Gate Power (t = 8.3 msec, T _C = 70°C)	P _{G(AV)}	0.35	W
Operating Junction Temperature Range	TJ	-40 to 110	°C
Storage Temperature Range	T _{stg}	-40 to 150	°C

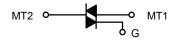
Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

 (V_{DRM} and V_{RRM} for all types can be applied on a continuous basis. Blocking voltages shall not be tested with a constant current source such that the voltage ratings of the devices are exceeded.

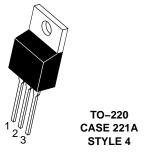


Littelfuse.com

TRIACS 12 AMPERES RMS 600 thru 800 VOLTS



MARKING DIAGRAM





(=	Μ,	or	N
---	---	----	----	---

A = Assembly Location

/ = Year

WW = Work Week

G = Pb-Free Package

PIN ASSIGNMENT			
1	Main Terminal 1		
2	Main Terminal 2		
3	Gate		
4	Main Terminal 2		

ORDERING INFORMATION

Device	Package	Shipping
MAC12SMG	TO-220 (Pb-Free)	50 Units / Rail
MAC12SNG	TO-220 (Pb-Free)	50 Units / Rail

THERMAL CHARACTERISTICS

Characteristic		Value	Unit
Thermal Resistance, Junction-to-Case Junction-to-Ambient	$R_{ heta JC} \ R_{ heta JA}$	2.2 62.5	°C/W
Maximum Lead Temperature for Soldering Purposes 1/8" from Case for 10 Seconds	T_L	260	°C

ELECTRICAL CHARACTERISTICS (T_{.I} = 25°C unless otherwise noted; Electricals apply in both directions)

Characteristic	Symbol	Min	Тур	Max	Unit	
OFF CHARACTERISTICS						
Peak Repetitive Blocking Current $(V_D = Rated \ V_{DRM}, \ V_{RRM}; \ Gate \ Open) \\ T_J = 25^{\circ}C \\ T_J = 110^{\circ}C$	I _{DRM} , I _{RRM}	- -	- -	0.01 2.0	mA	
ON CHARACTERISTICS						
Peak On-State Voltage (Note 2) (I _{TM} = ±17 A)	V _{TM}	-	_	1.85	V	
Gate Trigger Current (Continuous dc) (V_D = 12 V, R_L = 100 Ω) MT2(+), G(+) MT2(+), G(-) MT2(-), G(-)	I _{GT}	- - -	1.5 2.5 2.7	5.0 5.0 5.0	mA	
Holding Current (V _D = 12 V, Gate Open, Initiating Current = ±200 mA)	I _H	-	2.5	10	mA	
Latching Current ($V_D = 12 \text{ V}, I_G = 5 \text{ mA}$) MT2(+), G(+) MT2(+), G(-) MT2(-), G(-)	ΙL	- - -	3.0 5.0 3.0	15 20 15	mA	
Gate Trigger Voltage (Continuous dc) (V_D = 12 V, R_L = 100 Ω) MT2(+), G(+) MT2(+), G(-) MT2(-), G(-)	V _{GT}	0.45 0.45 0.45	0.68 0.62 0.67	1.5 1.5 1.5	V	
DYNAMIC CHARACTERISTICS	•	•	•	•		
Critical Rate of Change of Commutating Current ($V_D = 400 \text{ V}$, $I_{TM} = 3.5 \text{ A}$, Commutating dV/dt = 10 V/ μ s, Gate Open, $T_J = 110^{\circ}\text{C}$, f = 500 Hz, Snubber: Cs = 0.01 μ f, Rs = 15 Ω)	(di/dt) _c	8.0	10	-	A/ms	
Critical Rate of Rise of Off-State Voltage ($V_D = 67\% \ V_{DRM}$, Exponential Waveform, $R_{GK} = 1 \ K\Omega$, $T_J = 110^{\circ}C$)	dV/dt	15	40	-	V/μs	

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

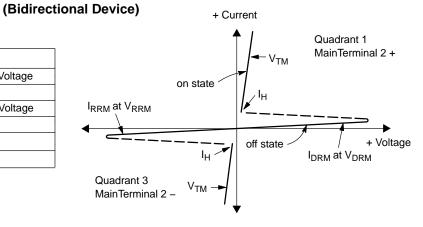
2. Pulse Test: Pulse Width \leq 2.0 ms, Duty Cycle \leq 2%.

Voltage Current Characteristic of Triacs

Symbol	Parameter
V_{DRM}	Peak Repetitive Forward Off State Voltage
I _{DRM}	Peak Forward Blocking Current
V_{RRM}	Peak Repetitive Reverse Off State Voltage
I _{RRM}	Peak Reverse Blocking Current
V_{TM}	Maximum On State Voltage
I _H	Holding Current

Repetitive Critical Rate of Rise of On-State Current

IPK = 50 A; PW = 40 μ sec; diG/dt = 1 A/ μ sec; Igt = 100 mA; f = 60 Hz

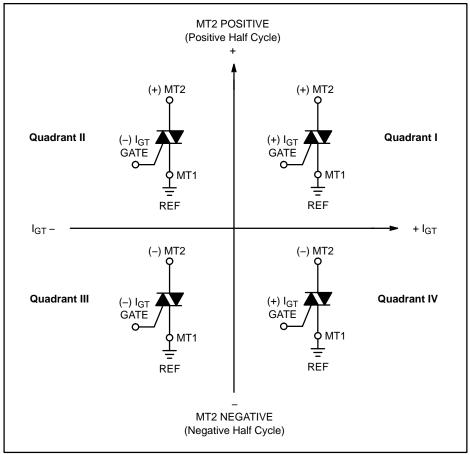


di/dt

10

A/μs

Quadrant Definitions for a Triac



All polarities are referenced to MT1.

With in-phase signals (using standard AC lines) quadrants I and III are used.

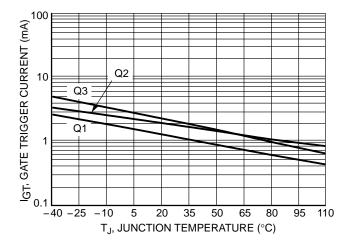


Figure 1. Typical Gate Trigger Current versus Junction Temperature

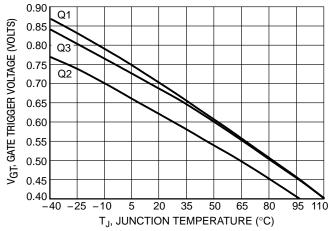
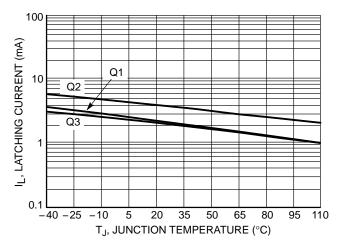


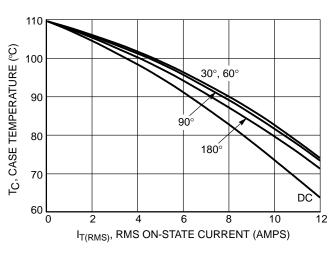
Figure 2. Typical Gate Trigger Voltage versus Junction Temperature



100 (YE) 100 MT2 Positive MT2 Negative MT2 Negative MT2 Negative T_J, JUNCTION TEMPERATURE (°C)

Figure 3. Typical Latching Current versus Junction Temperature

Figure 4. Typical Holding Current versus Junction Temperature



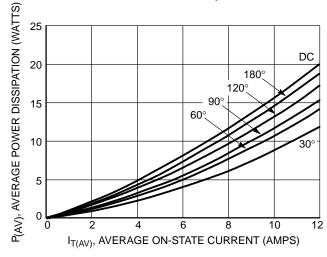
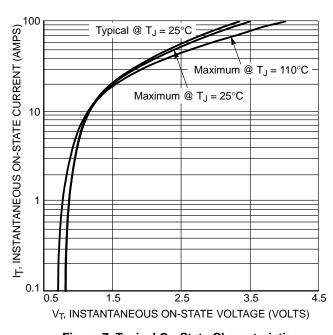


Figure 5. Typical RMS Current Derating

Figure 6. On-State Power Dissipation



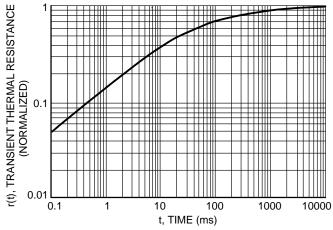
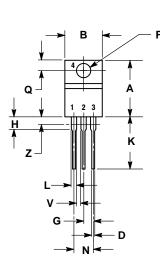
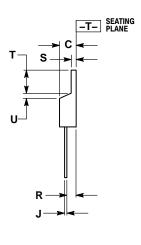


Figure 8. Typical Thermal Response

PACKAGE DIMENSIONS

TO-220 CASE 221A-09 **ISSUE AH**





- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.
- DIMENSION Z DEFINES A ZONE WHERE ALL BODY AND LEAD IRREGULARITIES ARE

	INCHES		MILLIMETERS	
DIM	MIN	MAX	MIN	MAX
Α	0.570	0.620	14.48	15.75
В	0.380	0.415	9.66	10.53
С	0.160	0.190	4.07	4.83
D	0.025	0.038	0.64	0.96
F	0.142	0.161	3.61	4.09
G	0.095	0.105	2.42	2.66
Н	0.110	0.161	2.80	4.10
J	0.014	0.024	0.36	0.61
K	0.500	0.562	12.70	14.27
L	0.045	0.060	1.15	1.52
N	0.190	0.210	4.83	5.33
Q	0.100	0.120	2.54	3.04
R	0.080	0.110	2.04	2.79
S	0.045	0.055	1.15	1.39
T	0.235	0.255	5.97	6.47
U	0.000	0.050	0.00	1.27
٧	0.045		1.15	
Z		0.080		2.04

STYLE 4:

PIN 1. MAIN TERMINAL 1

- 2. MAIN TERMINAL 2
- 3. GATE
- MAIN TERMINAL 2

Littelfuse products are not designed for, and shall not be used for, any purpose (including, without limitation, automotive, military, aerospace, medical, life-saving, life-sustaining or nuclear facility applications, devices intended for surgical implant into the body, or any other application in which the failure or lack of desired operation of the product may result in personal injury, death, or property damage) other than those expressly set forth in applicable Littelfuse product documentation. Warranties granted by Littelfuse shall be deemed void for products used for any purpose not expressly set forth in applicable Littelfuse documentation. Littelfuse shall not be liable for any claims or damages arising out of products used in applications not expressly intended by Littelfuse as set forth in applicable Littelfuse documentation. The sale and use of Littelfuse products is subject to Littelfuse Terms and Conditions of Sale, unless otherwise agreed by Littelfuse.

Littelfuse.com